

10/034,221

The Patent & Trademark Office acknowledges and has stamped hereon the date of receipt of the item checked below:

- | | |
|--|--|
| <input type="checkbox"/> New pat./design/PCT appln. | <input type="checkbox"/> Assignment & Recordal Cover Sheet |
| <input type="checkbox"/> Transmittal letter | <input type="checkbox"/> CC of priority document |
| <input type="checkbox"/> Fee Transmittal (PTO/SB/17) | <input type="checkbox"/> Application Data Sheet |
| <input type="checkbox"/> _____ pages spec./abstract | <input checked="" type="checkbox"/> Amendment/Response |
| <input type="checkbox"/> _____ pages of _____ claims | <input checked="" type="checkbox"/> Request for Extension |
| <input checked="" type="checkbox"/> 4 sheets of drawings | <input type="checkbox"/> Fee |
| <input type="checkbox"/> Declaration/Power | <input checked="" type="checkbox"/> Other <u>Amendment</u> |

APPLICANT: Seung Ho PYISERIAL NO: 10/034,221

WWP:rts

FILED: 12-28-01

TITLE: METHOD FOR FABRICATING A SEMICONDUCTOR
EPITAXIAL WAFER HAVING DOPED COARBON AND A SEMI
CONDUCTOR EPITAXIAL WAFER
DOCKET 2755 DATE: 8-29-03



Mitchell

fax 5.71-273 1032